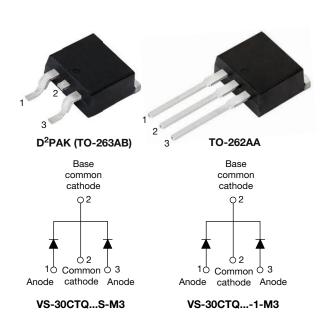
# VS-30CTQ0.0S-M3, VS-30CTQ0.0-1-M3 Series

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# High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 15 A				
$V_{R}$	50 V, 60 V				
V <sub>F</sub> at I <sub>F</sub>	0.56 V				
I <sub>RM</sub> typ.	45 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	13 mJ				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- · Very low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UN							
I <sub>F(AV)</sub>	Rectangular waveform	30	Α				
V <sub>RRM</sub>		50/60	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1000	Α				
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.56	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-30CTQ050S-M3 VS-30CTQ060S-M3 VS-30CTQ060-1-M3 UNITS						
Maximum DC reverse voltage	$V_R$	50	60	V		
Maximum working peak reverse voltage	$V_{RWM}$	50	00	V		



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ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum average per device forward current See fig. 5 per leg					30				
		I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 105 °C, rectangular waveform		15	A			
	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	1000	_ ^			
surge current per leg See fig. 7		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	260				
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 1.50  \text{A},  L = 11.5  \text{mH}$		13	mJ			
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 µs Frequency limited by T <sub>-I</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.50	Α			

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		15 A	T <sub>.1</sub> = 25 °C	0.62				
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	30 A	1j=25 C	0.82	V			
See fig. 1	V <sub>FM</sub> ('')	15 A	T 105 °C	0.56				
		30 A	T <sub>J</sub> = 125 °C	0.71				
Maximum rayaraa laakaga ayrrant nar lag	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V - Poted V	0.80	mA			
Maximum reverse leakage current per leg		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	160				
Typical reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	45	mA			
Threshold voltage	V <sub>F(TO)</sub>	T T mayimum		0.39	V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		8.47	mΩ			
Maximum junction capacitance per leg	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	720	pF				
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 r	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs			

### Note

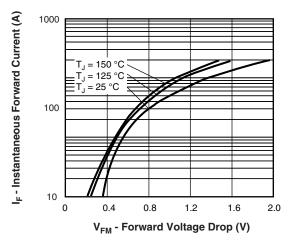
 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to 150	°C			
Maximum thermal resistance, junction to case per leg		Р	DC operation	3.25	°C/W			
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC Operation	1.63				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking dayioo			Case style D <sup>2</sup> PAK (TO-263AB)		Q050S Q060S			
Marking device			Case style TO-262AA	30CTC				



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1000 100 = 150 °C I<sub>R</sub> -Reverse Current (mA) T<sub>J</sub> = 125 °C 10 = 100 °C = 75 °C 0.1 = 50 °C: T<sub>1</sub> = 25 °C 0.01 0.001 60 0 10 30 40 50 V<sub>R</sub> - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

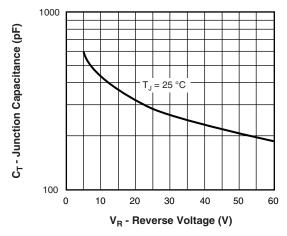


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

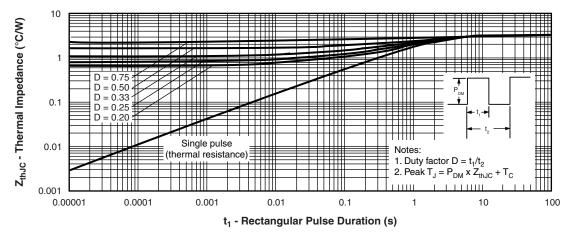


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

Allowable Case Temperature (°C)

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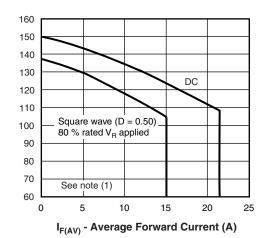


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

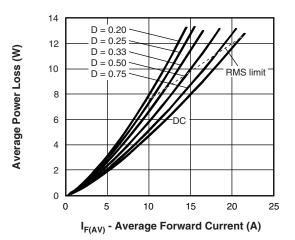


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

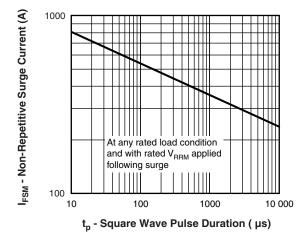


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

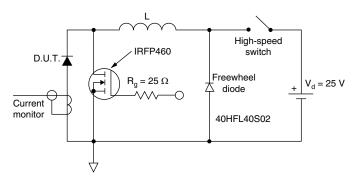


Fig. 8 - Unclamped Inductive Test Circuit

### Note

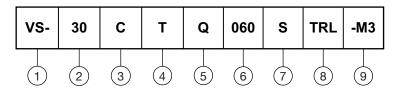
1) Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 10 V

# VS-30CTQ0.0S-M3, VS-30CTQ0.0-1-M3 Series

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### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

2 - Current rating (30 A)

**3** - Circuit configuration: C = common cathode

**4** - T = TO-220

5 - Schottky "Q" series

050 = 50 V 060 = 60 V

7 - • S =  $D^2PAK$  (TO-263AB)

• -1 = TO-262AA

None = tube

• TRL = tape and reel (left oriented - for D<sup>2</sup>PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D<sup>2</sup>PAK (TO-263AB) only)

9 - - M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-30CTQ050S-M3	50	1000	Antistatic plastic tubes				
VS-30CTQ050STRR-M3	800	800	13" diameter reel				
VS-30CTQ050STRL-M3	800	800	13" diameter reel				
VS-30CTQ050-1-M3	50	1000	Antistatic plastic tubes				
VS-30CTQ060S-M3	50	1000	Antistatic plastic tubes				
VS-30CTQ060STRR-M3	800	800	13" diameter reel				
VS-30CTQ060STRL-M3	800	800	13" diameter reel				
VS-30CTQ060-1-M3	50	1000	Antistatic plastic tubes				

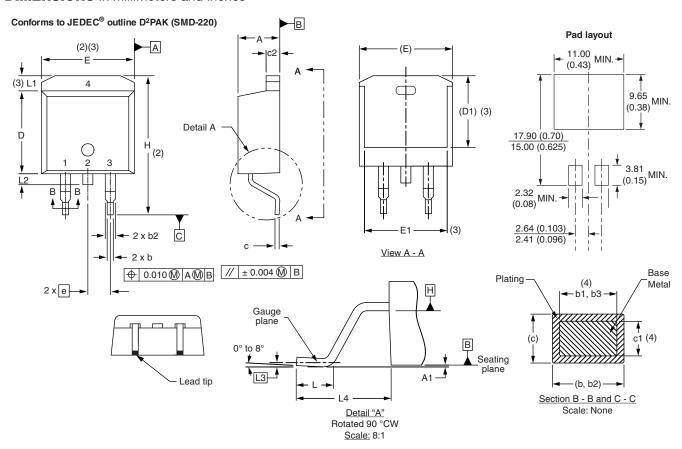
LINKS TO RELATED DOCUMENTS						
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164				
Dimensions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				



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# D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES SYMBOL		MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

### Notes

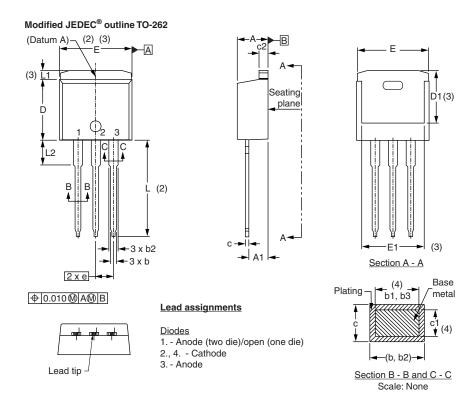
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



## Vishay Semiconductors

## **TO-262**

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	METERS	INC	INCHES			
STINIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
Е	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	2.54 BSC		) BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- 5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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